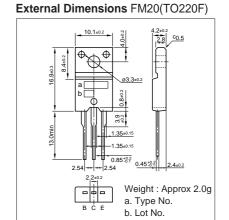
2SC413

Silicon NPN Epitaxial Planar Transistor (High Voltage and High Speed Switching Transistor)

Application: Switching Regulator and General Purpose

Absolute	(Ta=25°C)	
Symbol	2SC4130	Unit
Vсво	500	V
VCEO	400	V
VEBO	10	V
Ic	7(Pulse14)	А
Ів	2	А
Pc	30(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

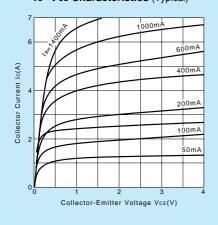
Electrical Cl	naracteristics	(Ta=25°C)		
Symbol	Conditions	2SC4130	Unit	
Ісво	Vcb=500V	100max	μΑ	
Г ЕВО	VEB=10V	100max	μΑ	
V(BR)CEO	Ic=25mA	400min	V	
hfe	Vce=4V, Ic=3A	10 to 30		
Vce(sat)	Ic=3A, IB=0.6A	0.5max	V	
VBE(sat)	Ic=3A, IB=0.6A	1.3max	V	
fт	Vce=12V, Ie=-0.5A	15typ	MHz	
Сов	VcB=10V, f=1MHz	50typ	рF	



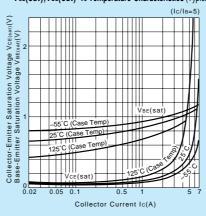
Typical	Cwitching	Characteristics	Camman	Emitter)
I ypicai	Switching	Characteristics	(Common	⊑mitter)

			•		,				
Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
200	67	3	10	-5	0.3	-0.6	1max	2.2max	0.5max

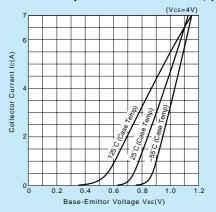




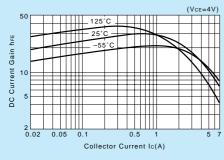
VcE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)



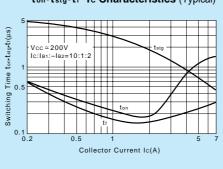
Ic-VBE Temperature Characteristics (Typical)

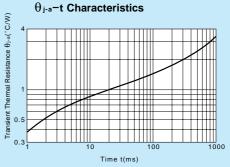


hfe-Ic Characteristics (Typical)

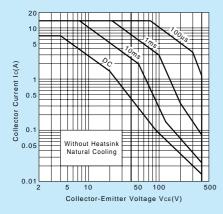


ton•tstg•tf-Ic Characteristics (Typical)

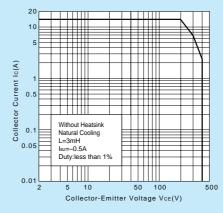




Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

